## Abstract Submitted for the MAR07 Meeting of The American Physical Society

Piezomagnetism in Epitaxial Cr<sub>2</sub>O<sub>3</sub> Thin Films<sup>1</sup> YI WANG, SARBESWAR SAHOO, CHRISTIAN BINEK, University of Nebraska-Lincoln, BINEK TEAM — Recently, the magnetoelectric material Cr<sub>2</sub>O<sub>3</sub> attracted renewed interest due to its potential for future spintronics applications which can be realized by novel magnetic thin film heterostructures [1]. Here we study thin films of Cr<sub>2</sub>O<sub>3</sub> (111) on c-Al<sub>2</sub>O<sub>3</sub> (111) substrate which are grown by thermal evaporation of Cr metal in an O<sub>2</sub> atmosphere. X-ray diffraction data reveal stoichiometric epitaxially grown  $Cr_2O_3$  (111) films. Owing to a lattice mismatch of  $\sim 4\%$  at the interface between the Al<sub>2</sub>O<sub>3</sub>substrate and the film we observe a strong stress induced piezomagnetic moment in the  $Cr_2O_3$  film. We measure the temperature dependence of this piezomoment by Superconducting Quantum Interference Device (SQUID) magnetometry and Kerr rotation. The presence of high inherent stress, a significant piezomagnetic moment and the possibility to realize high electric fields makes our Cr<sub>2</sub>O<sub>3</sub> thin films ideal candidates for the challenging quest of the symmetry allowed but hitherto undiscovered piezomagnetoelectric effect. [1] Ch. Binek, B. Doudin, J. Phys. Condens. Matter 17, L39 (2005).

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